

PI5A124

Wide Bandwidth Analog Switches

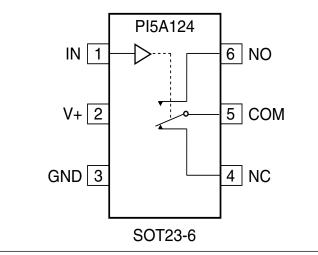
Features

- Single-Supply Operation (+2V to +6V)
- Rail-to-Rail Analog Signal Dynamic Range
- Low On-Resistance (6Ω typ. with 5V supply) Minimizes Distortion and Error Voltages
- On-Resistance Flatness, 3Ω typ.
- Low Charge Injection Reduces Glitch Errors. Q = 4pC typ.
- High Speed. $t_{ON} = 10$ ns typ.
- Wide -3dB Bandwidth: 326 MHz (typ.)
- High-Current Channel Capability: >100mA
- TTL/CMOS Logic Compatible
- Low Power Consumption (0.5µW typ)
- · Small outline transistor package minimizes board area
- Packaging (Pb-free & Green available):
- 6-pin 65-mil wide SOT23 (T) for PI5A124

Applications

- · Audio, Video Switching, and Routing
- Battery-Powered Communication Systems
- Computer Peripherals
- Telecommunications
- Portable Instrumentation
- · Mechanical Relay Replacement
- Cell Phones
- PDAs

Functional Diagrams/Pin Configurations



Switches shown for Logic "0" input

Description

The PI5A124 are analog switches designed for single-supply operation. These high-precision devices are ideal for low-distortion audio, video, signal switching and routing.

These switches are fully specified with +5V, and +3.3V supplies. With +5V, they guarantee <10 Ω On-Resistance. On-Resistance matching between channels is within 2 Ω . On-Resistance flatness is less than 55 Ω over the specified range. These switches also guarantee fast switching speeds (t_{ON} <20ns).

These products are available in 6-pin SOT23 plastic packages for operation over the industrial $(-40^{\circ}C \text{ to } +85^{\circ}C)$ temperature range.

Truth Tables

	PI5A124				
LOGIC	NC	NO			
0	ON	OFF			
1	OFF	ON			

Absolute Maximum Ratings

Absolute Maximum Ratings	Thermal Information
Voltages Referenced to Gnd	Continuous Power Dissipation
V+0.5V to +7V	SOT23-6 (derate 7mW/°C above +70°C) 550mW
V_{IN} , V_{COM} , V_{NC} , V_{NO} (Note 1)0.5V to V++2V or 30mA, whichever occurs first	Storage Temperature65°C to +150°C
Current (any terminal)±25mA	Lead Temperature (soldering, 10s) +300°C
Peak Current, COM, NO, NC	Note 1:
(Pulsed at 1ms, 10% duty cycle)±25mA	Signals on NC, NO, COM, or IN exceeding V+ or GND are clamped by internal diodes. Limit forward diode current to 30mA.

Caution: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications - Single +5V Supply

$(V + = +5V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp.(°C)	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units
Analog Switch							
Analog Signal Range ⁽³⁾	VANALOG		Full	0		V+	v
On-Resistance	Pour		25		7.2	10	
Oll-Resistance	R _{ON}	V + = 4.5V,	Full			12	
On-Resistance		$I_{COM} = -30 \text{mA},$	25		0.2	2	
Match Between Channels ⁽⁴⁾	ΔR_{ON}	$V_{\rm NO}$ or $V_{\rm NC}$ = +2.5V	Full			4	Ω
On-Resistance Flat- ness ⁽⁵⁾	R _{FLAT(ON})	V+=5V,	25		2.72	3.5	
		$I_{COM} = -30 \text{mA},$ V _{NO} or V _{NC} = 1V, 2.5V, 4V	Full			4	
NO or NC Off Leak- age Current ⁽⁶⁾	I _{NO(OFF)} or I _{NC(OFF)}	V+=5.5V,	25		0.18		
		$V_{COM} = 0V,$ V_{NO} or $V_{NC} = 4.5V$	Full	-1		150	
COM Off Leakage Current ⁽⁶⁾	I _{COM(OFF)}	$V_{+} = 5.5V, V_{COM} = +4.5V,$ $V_{NO} \text{ or } V_{NC} = \pm 0V$	25		0.20		
			Full	-1		150	nA
COM On Leakage Current ⁽⁶⁾	I _{COM(ON)}	V+ = 5.5V,	25		0.20		1
		$V_{COM} = +4.5V$ V_{NO} or $V_{NC} = +4.5V$	Full	-1		50	

Electrical Specifications - Single +5V Supply

 $(V + = +5V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp(°C)	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units
Logic Input							
Input High Voltage	V _{IH}	Guaranteed logic High Level		2			
Input Low Voltage	V _{IL}	Guaranteed logic Low Level				0.8	V
Input Current with Voltage High	I _{INH}	$V_{IN} = 2.4V$, all others = $0.8V$	Full	-1	0.005	1	
Input Current with Voltage Low	I _{INL}	$V_{IN} = 0.8V$, all others = 2.4V		-1	0.005	1	μΑ
Dynamic							
T		V+=5V, Figure 1	25		7	15	
Turn-On Time	t _{ON}		Full			20	- ns
T 0.00 T			25		1	7	
Turn-Off Time	t _{OFF}		Full			10	
Charge Injection ⁽³⁾	Q	$C_L = 1nF, V_{GEN} = 0V,$ $R_{GEN} = 0\Omega$, Figure 2			1.6	10	pC
Off Isolation	O _{IRR}	$R_L = 50\Omega$, $C_L = 5pF$, f = 10MHz, Figure 3			-43		dB
Crosstalk ⁽⁸⁾	X _{TALK}	$R_L = 50\Omega, C_L = 5pF,$ f = 10MHz, Figure 4	25		-43		
NC or NO Capacitance	C _(OFF)	C = 11 II = Eisen 5			5.5		pF
COM Off Capacitance	C _{COM(OFF)}	f = 1kHz, Figure 5			5.5		
COM On Capacitance	C _{COM(ON)}	f = 1kHz, Figure 6			13		
-3dB Bandwidth	BW	$R_L = 50\Omega$, Figure 7	Full		326		MHz
Supply							
Power-Supply Range	V+		E 11	2		6	V
Positve Supply Current	I+	$V + = 5.5V, V_{IN} = 0V \text{ or } V +$	— Full			1	μA

Notes:

1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.

2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.

- 3. Guaranteed by design
- 4. $\Delta R_{ON} = R_{ON} \max R_{ON} \min$
- 5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
- 6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- 7. Off Isolation = $20\log_{10} [V_{COM} / (V_{NO} \text{ or } V_{NC})]$. See Figure 3.
- 8. Between any two switches. See Figure 4.

Parameter	Symbol	Conditions	Temp.(°C)	Min.(1)	Typ.(2)	Max.(1)	Units
Analog Switch							
Analog Signal Range ⁽³⁾	VANALOG			0		V+	V
On-Resistance		$V+=3V$, $I_{COM}=-30mA$, V_{NO} or $V_{NC}=1.5V$	25		12	18	-
On-Resistance	R _{ON}		Full			22	
On-Resistance Match	AD any		25		1	1	Ω
Between Channels ⁽⁴⁾	ΔR_{ON}	$V + = 3.3V$, $I_{COM} = -30mA$,	Full			2	
On-Resistance Flat-	B ELATION	$V_{\rm NO} \text{ or } V_{\rm NC} = 0.8 \text{V}, 2.5 \text{V}$	25		0.5	4	-
ness ^(3,5)	R _{FLAT(ON)}		Full			5	
Dynamic							
T On Time		V+ = 3.3V, V _{NO} or V _{NC} = 1.5V, Figure 1	25		15	25	ns
Turn-On Time	t _{ON}		Full			40	
T Off Times	4		25		1.5	12	
Turn-Off Time	t _{OFF}		Full			20	
Charge Injection ⁽³⁾	Q	$C_L = 1nF, V_{GEN} = 0V,$ $R_{GEN} = 0V,$ Figure 2	25		1.3	10	pC
Supply							
Positve Supply Current	I+	V+ = 3.6V, V_{IN} = 0V or V+ All Channels on or off	Full			1	μA
Logic Input							
Input High Voltage	V _{IH}	Guaranteed logic high level	Full	2			v
Input Low Voltage	V _{IL}	Guaranteed logic low level	Full			0.8	v
Input High Current	I _{INH}	$V_{\rm IN} = 2.4$ V, all others = 0.8V	Full	-1		1	
Input Low Current	I _{INL}	$V_{IN} = 0.8V$, all others $= 2.4V$	Full	-1		1	μΑ

Electrical Specifications - Single +3.3V Supply (V+ = +3.3V \pm 10%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)

Test Circuits/Timing Diagrams

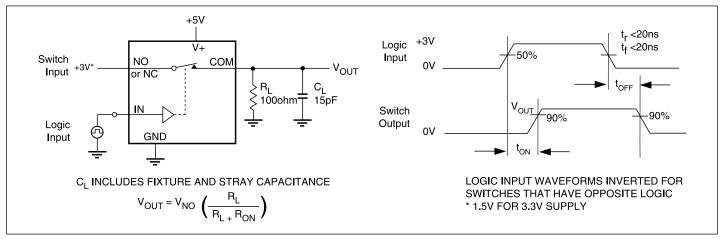


Figure 1. Switching Time

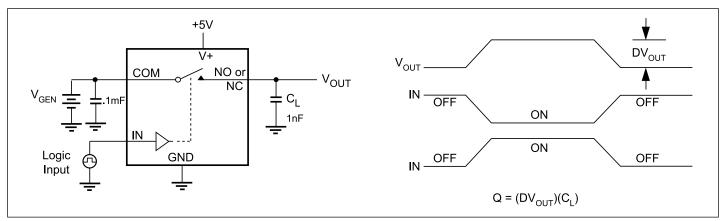


Figure 2. Charge Injection

Test Circuits/Timing Diagrams

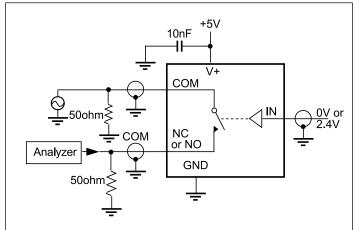


Figure 3. Off Isolation

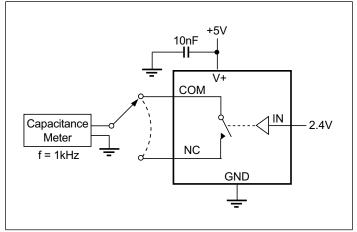


Figure 5. Channel-Off Capacitance

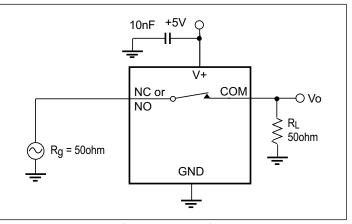


Figure 7. Bandwidth

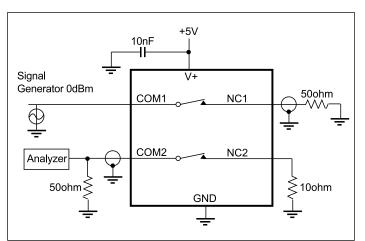


Figure 4. Crosstalk (124 only)

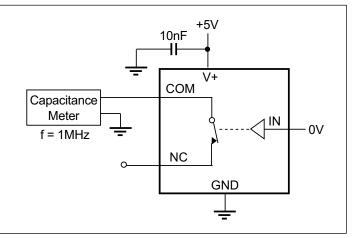
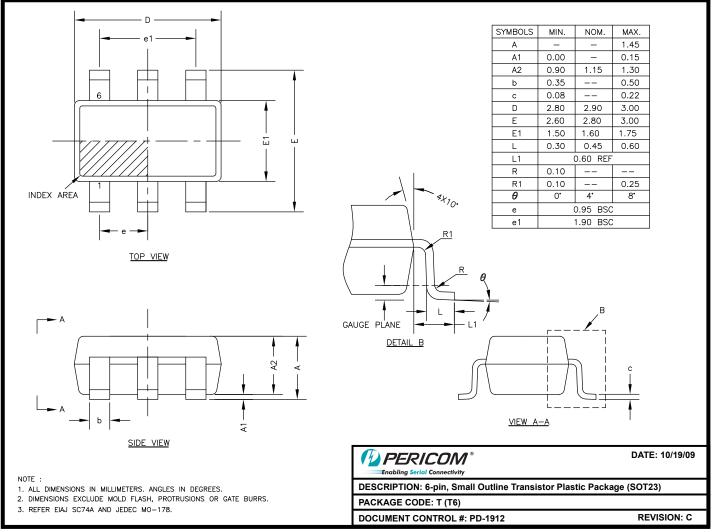


Figure 6. Channel-On Capacitance

Packaging Mechanical: SOT23 (T)



09-0131

Note:

• For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

Ordering Information

Ordeing	Code	Packaging Code	Package Type	Top Marking
PI5A124	4TE	Т	6-pin, Small Outline Transistor Plastic Package (SOT23)	ZT

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free and Green
- Adding an X suffix = Tape/Reel

Pericom Semiconductor Corporation • 1-800-435-2336 • www.pericom.com